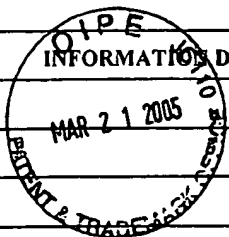


⁶Applicant is to place a check mark here if English language Translation is attached.

PTO/SB/08A (Substitute for form 1449/PTO)		Attorney Docket No.: 023-0031
		Application No.: 10/729,843
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		First Named Inventor: Luca G. Fasoli et al.
		Filing Date: December 5, 2003
		Group Art Unit: 2824
		Examiner Name: Pho-M-Luu VTN
Sheet 1 of 5		Date Submitted: March 15, 2005



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Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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VTN	AN	JA 62-142363	06-25-1987			
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	AP	JA-2001-358237	12-26-2001			
VTN	AQ	JA-2002-280467	09-27-2002			
Examiner Signature: <i>[Signature]</i>			Date Considered: 1/7/06			

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Applicant's unique citation designation number (optional).

²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04.

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⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document.

⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible.

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PTO/SB/08A (Substitute for form 1449/PTO)	Attorney Docket No.: 023-0031
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT	First Named Inventor: Luca G. Fasoli et al.
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	Examiner Name: Pho M. Luu VTN
Sheet 2 of 5	Date Submitted: March 15, 2005

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	BE					
	BF					
	BG					
	BH					
Examiner Signature		Pho M. Luu		Date Considered	1/7/06	

PTO/SB/08A (Substitute for form 1449/PTO)	Attorney Docket No.: 023-0031
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(Continuation Sheet)	Filing Date: December 5, 2003
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	Examiner Name: Pho M. Lma VTN
Sheet 3 of 5	Date Submitted: March 15, 2005

U.S. PATENT DOCUMENTS

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	BV					
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Examiner Signature		Date Considered		1/7/06		

PTO/SB/08A (Substitute for form 1449/PTO)	Attorney Docket No.: 023-0031
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(Continuation Sheet)	Filing Date: December 5, 2003
	Group Art Unit: 2824
	Examiner Name: Pho M. Luu
Sheet 4 of 5	Date Submitted: March 15, 2005

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VTN	BZ	6,515,888	02-04-2003	Johnson et al.	
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	CM					
	CN					
	CO					
	CP					
Examiner Signature		[Signature]		Date Considered	VTN	

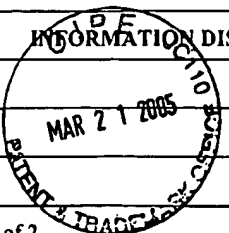
PTO/SB/08A (Substitute for form 1449/PTO)	Attorney Docket No.: 023-0031
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT	First Named Inventor: Luca G. Fasoli et al.
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	Examiner Name: Pho M. Luu VTN
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VTN	CQ	US-2002/0021587 A1.	02-21-2002	Sakui et al.	
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	DB				
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	DD					
	DE					
	DF					
	DG					
Examiner Signature: <i>Pho M. Luu</i>				Date Considered	1/7/06	

PTO/SB/08B (Substitute for form 1449/PTO)		Attorney Docket No.: 023-0031
		Application No.: 10/729,843
		First Named Inventor: Luca G. Fasoli et al.
		Filing Date: December 5, 2003
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		Examiner Name: Pho-M. Luu VTN
		Date Submitted: March 15, 2005
Sheet 1 of 2		

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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Examiner Signature			Date Considered
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Applicant's unique citation designation number (optional).

²Applicant is to place a check mark here if English language Translation is attached.

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT	First Named Inventor: Luca G. Fasoli et al.
(Continuation Sheet)	Filing Date: December 5, 2003
	Group Art Unit: 2824
	Examiner Name: Pho M. Luu VTN
Sheet 2 of 2	Date Submitted: March 15, 2005

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Examiner Signature		Date Considered	1/7/16

U.S. Department of Commerce, Patent and Trademark Office				Attorney Docket No.: 023-0031		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Application No.: 10/729,843		
(Use several sheets if necessary)				Applicant(s): Luca G. Fasoli et al.		
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				Date Submitted: September 20, 2004		
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*Examiner Initial		Document Number	Date	Name		
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		Document	Date	Country	Yes	No
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	AN					
	AP					
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)						
	AR					
	AS					
	AT					
Examiner: <i>Orhu Ng</i>		Date Considered: 1/7/00				
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